

SAMTM Data Sheet SAM-940-47-2ps-x, λ = 940 nm

Laser wavelength $\lambda = 940 \text{ nm}$

High reflection band $\lambda = 900 ... 980 \text{ nm}$

Absorbance $A_0 = 47 \%$ Modulation depth $\Delta R = 29 \%$ Non-saturable loss $A_{ns} = 18 \%$

Saturation fluence $\Phi_{\text{sat}} = 70 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau \sim 2 \text{ ps}$

Damage threshold $\Phi = 1 \text{ mJ/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option \mathbf{x} denotes the type of mounting as follows:

x = 0 unmounted

 $x = 12.7 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 12.7 mm \varnothing $x = 25.4 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 25.4 mm \varnothing $x = 12.7 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing $x = 25.4 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing x = FCmounted on a 2 m monomode fiber cable with FC connector

Low intensity spectral reflectance

